

## **Description**

The IRLM0060TRPBF uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.



**SOT-23** 

#### **General Features**

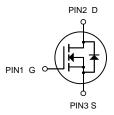
 $V_{DS} = 60V I_D = 3A$  $R_{DS(ON)} < 89m\Omega @ V_{GS} = 10V$ 

## **Application**

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

### **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
IRLM0060TRPBF	SOT-23	S10	3000PCS

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
VDS	Drain-Source Voltage	60	V
V <sub>G</sub> s	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	3	А
Ім	Drain Current-Pulsed (Note 1)	10	А
P <sub>D</sub>	Maximum Power Dissipation	1.7	W
TJ,Tstg	Operating Junction and Storage Temperature Range	-55 To 150	°C
Reja	Thermal Resistance,Junction-to-Ambient (Note 2)	73.5	°C/W

# N-Channel Enhancement Mode MOSFET

Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

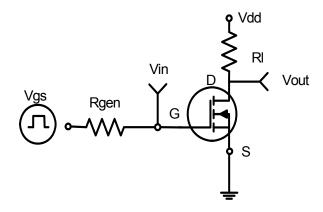
				±100	nA	
On Characteristics (Note 3)						
S(th)	$V_{DS}$ = $V_{GS}$ , $I_D$ =250 $\mu$ A	0.8	1.3	2.0	V	
	$V_{GS}$ =10V, $I_D$ =3A	-	80	89	mΩ	
S(ON)	$V_{GS}$ =4.5 $V$ , $I_{D}$ =1.5 $A$	-	89	115	mΩ	
-s	V <sub>DS</sub> =15V,I <sub>D</sub> =2A		3	-	S	
lss	\/ -20\/\/ -0\/	-	510	-	PF	
oss		-	34	-	PF	
rss	F=1.UIVIHZ	-	26	-	PF	
on)		-	6	-	nS	
r	V <sub>DD</sub> =30V,I <sub>D</sub> =1.5A	-	15	-	nS	
off)	$V_{GS}$ =10 $V$ , $R_{GEN}$ =1 $\Omega$	-	15	-	nS	
f		-	10	-	nS	
<b>Q</b> g	\/ -20\/1 -24	-	7.5	-	nC	
gs		-	1.4	-	nC	
gd	VGS-4.5V	-	3	-	nC	
Drain-Source Diode Characteristics						
SD	V <sub>GS</sub> =0V,I <sub>S</sub> =3A	-	-	1.2	V	
S		-	-	3	Α	
	ss	$\begin{array}{c c} V_{GS} = 10V, \ I_D = 3A \\ \hline V_{GS} = 4.5V, \ I_D = 1.5A \\ \hline V_{DS} = 15V, I_D = 2A \\ \hline \\ SS & V_{DS} = 30V, V_{GS} = 0V, \\ \hline F = 1.0MHz \\ \hline \\ SS & V_{DD} = 30V, I_D = 1.5A \\ \hline V_{GS} = 10V, R_{GEN} = 1\Omega \\ \hline \\ f & V_{DS} = 30V, I_D = 3A, \\ \hline V_{GS} = 4.5V \\ \hline \\ SD & V_{GS} = 0V, I_S = 3A \\ \hline \end{array}$	$\begin{array}{c} V_{GS} = 10 \text{V}, \ I_D = 3 \text{A} \\ V_{GS} = 4.5 \text{V}, \ I_D = 1.5 \text{A} \\ \end{array} \\ \begin{array}{c} V_{DS} = 15 \text{V}, \ I_D = 2 \text{A} \\ \end{array} \\ \begin{array}{c} SS \\ SS \\ SS \\ SS \\ \end{array} \\ \begin{array}{c} V_{DS} = 30 \text{V}, \ V_{GS} = 0 \text{V}, \\ F = 1.0 \text{MHz} \\ \end{array} \\ \begin{array}{c} - \\ - \\ - \\ - \\ - \\ - \\ - \\ - \\ - \\ - $	$\begin{array}{c} V_{GS} = 10 \text{V}, \ I_D = 3 \text{A} & - & 80 \\ \hline V_{GS} = 4.5 \text{V}, \ I_D = 1.5 \text{A} & - & 89 \\ \hline v_{SS} & V_{DS} = 15 \text{V}, I_D = 2 \text{A} & 3 \\ \hline v_{SS} & V_{DS} = 30 \text{V}, V_{GS} = 0 \text{V}, \\ \hline F = 1.0 \text{MHz} & - & 34 \\ \hline v_{SS} & - & - & 6 \\ \hline v_{DD} = 30 \text{V}, I_D = 1.5 \text{A} & - & 15 \\ \hline v_{Off} & V_{GS} = 10 \text{V}, R_{GEN} = 1 \Omega & - & 15 \\ \hline v_{DS} = 30 \text{V}, I_D = 3 \text{A}, \\ \hline v_{GS} = 4.5 \text{V} & - & 3 \\ \hline v_{SS} = 0 \text{V}, I_S = 3 \text{A} & - & - \\ \hline v_{SS} = 0 \text{V}, I_S = 3 \text{A} & - $	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	

#### Notes:

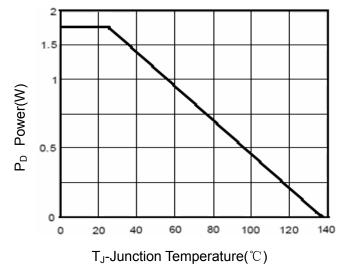
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

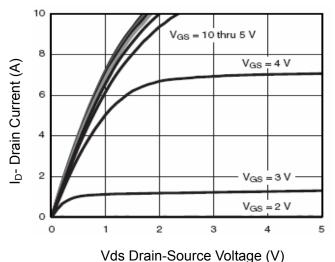


Figure 5 Output Characteristics

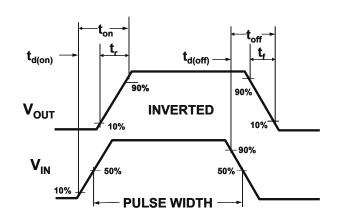
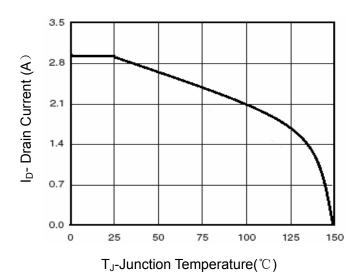


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

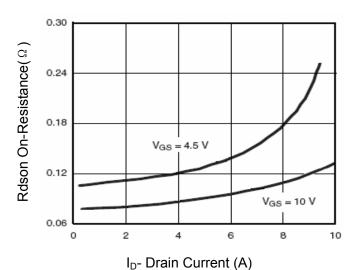
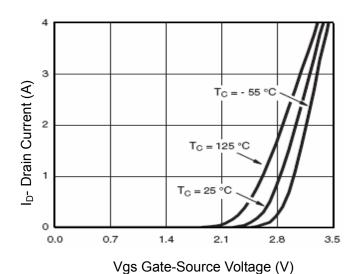
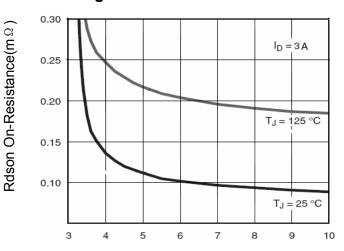


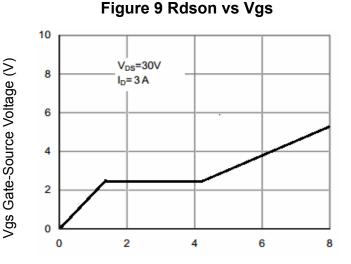
Figure 6 Drain-Source On-Resistance



**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)



Qg Gate Charge (nC) Figure 11 Gate Charge

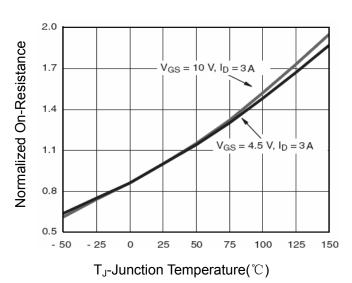


Figure 8 Drain-Source On-Resistance

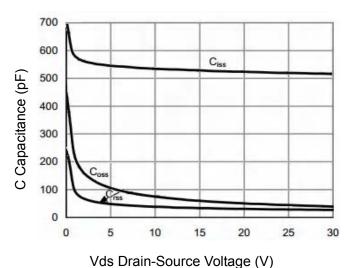


Figure 10 Capacitance vs Vds

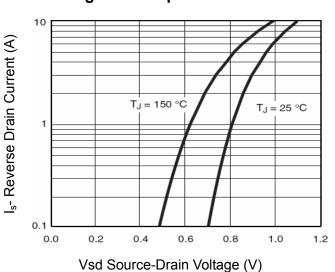


Figure 12 Source- Drain Diode Forward

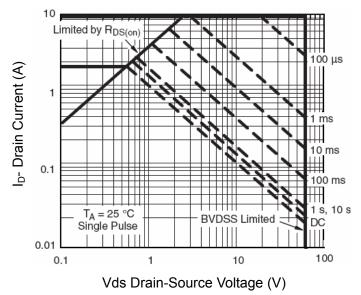
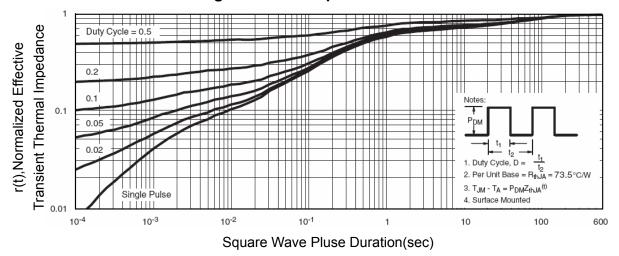


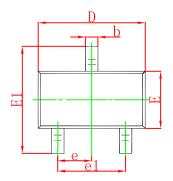
Figure 13 Safe Operation Area

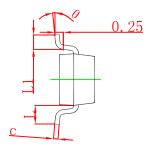


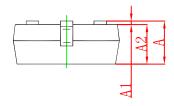
**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23 Package Outline Dimensions**

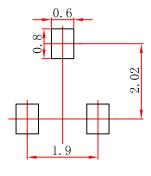






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# **SOT-23 Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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